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Shih

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(54) **STRUCTURE OF TFT PLANAR DISPLAY PANEL**

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(58) **Field of Search** 257/59, 66, 72, 257/347; 348/43, 44

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(57) **ABSTRACT**

A structure of a thin film transistor (TFT) planar display panel is disclosed. The structure includes a light-transmissible substrate, a buffer layer formed on the light-transmissible substrate, a top-gate TFT structure formed on the buffer layer and including a channel region, and a light-shielding structure formed between a back light source and the top-gate TFT structure, and substantially aligned with the channel region for protecting the channel region from illumination of the back light source. The process for manufacturing a TFT planar display panel is also disclosed.

16 Claims, 8 Drawing Sheets